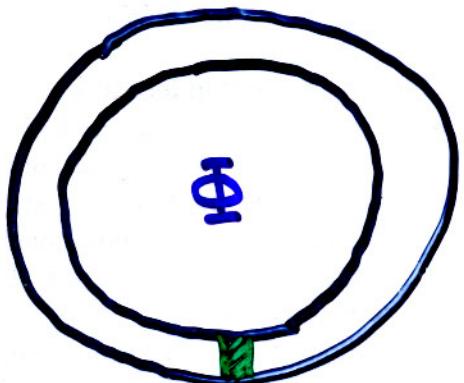


SUPERPOSITION AND ENTANGLEMENT

OF STATES OF SOLID-STATE QUBITS.

A. Flux-mode SQUID:

Superposition:

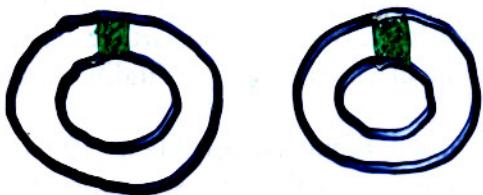


$$\Psi(\mathcal{J}, \Phi) \sim$$

$$a \psi_L(\mathcal{J}) \chi_L(\Phi) + b \psi_R(\mathcal{J}) \chi_R(\Phi)$$

$$\langle \psi_L(\mathcal{J}) | \psi_R(\mathcal{J}) \rangle = 0$$

Entanglement:



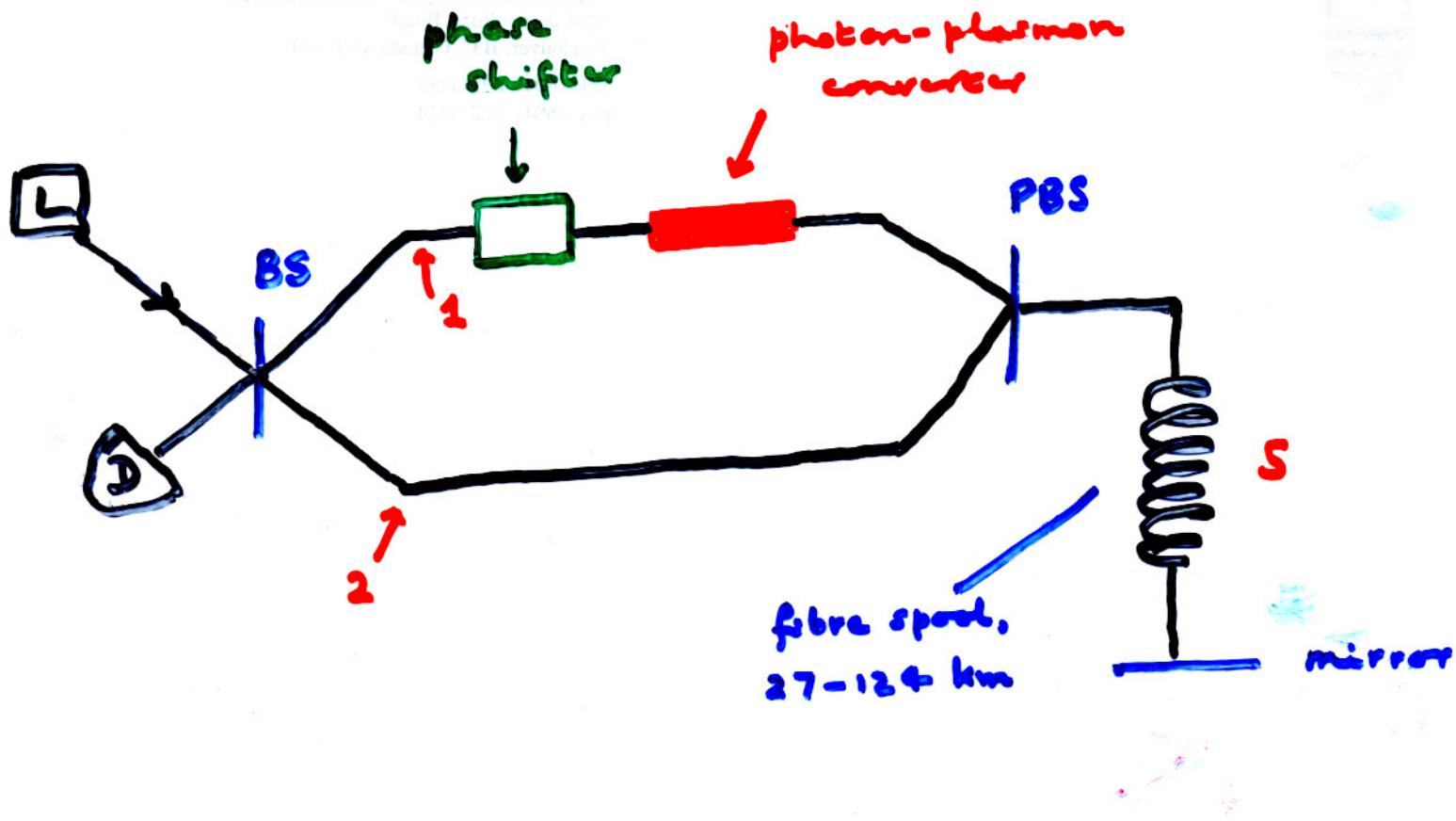
$$\Psi(\mathcal{J}_1, \Phi_1, \mathcal{J}_2, \Phi_2)$$

$$\sim a \psi_L(\mathcal{J}_1) \chi_L(\Phi_1) \psi_R(\mathcal{J}_2) \chi_R(\Phi_2) -$$

$$b \psi_R(\mathcal{J}_1) \chi_R(\Phi_1) \psi_L(\mathcal{J}_2) \chi_L(\Phi_2)$$

again, $\langle \psi_L(\mathcal{J}_1) | \psi_R(\mathcal{J}_2) \rangle = \langle \psi_R(\mathcal{J}_1) | \psi_L(\mathcal{J}_2) \rangle = 0$

B. Surface plasmons (S. Farcl et al., NJP 8, 13 (2006))



Path A: L → 1 → PPC → S → 2 → D

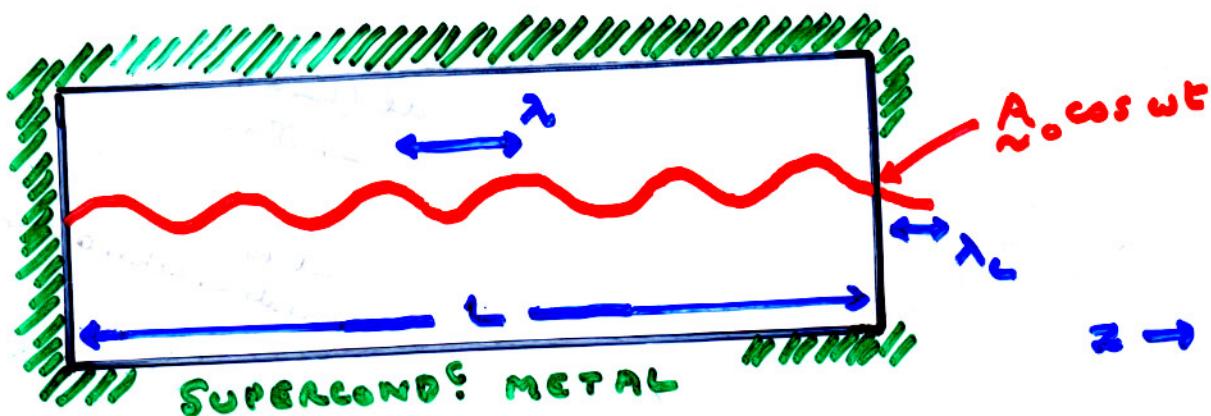
Path B: L → 2 → S → PPC → 1 → D

The time difference at which the photon is converted into a surface plasmon reaches a max. value > 1 msec!

Nevertheless, "fringe visibility" > 99%!

?

DIGRESSION: PHOTON CONFINED BY WALLS



The electrons in the walls are essentially to confine the photon. Does this mean they are strongly unscattered with it? Assume $\omega \ll \omega_p$ ← plasma freq of sup?

i.e.:

$$\Psi \sim a|0\rangle + b|1\rangle \Rightarrow \Psi \sim a|0\rangle |x_0\rangle + b|1\rangle |x_1\rangle$$

naive description

states of electrons

How orthogonal are x_0 and x_1 ?

Ans:

$$H_{wall} = \int d\mathbf{r} \left\{ + \frac{\mathbf{J}^2(r)}{\epsilon_0 \omega_p^2} + \mathbf{J}(r) \cdot \mathbf{A}(r) + (\nabla \times \mathbf{A})^2 / 2\mu_0 + \epsilon_0 \mathbf{J}^2 \right\}$$

$$\Rightarrow \mathbf{J}(r) = -\epsilon_0 \omega_p^2 \mathbf{A}(r)$$

So:

$$\Psi\{\tilde{J}(z), \tilde{A}(z)\} = \tilde{\delta}(J(z) + \epsilon_0 \omega_p^2 A(z)) \Psi\{\tilde{A}(z)\}$$

so, gr. of orthogonality of electron states reduces
to that of states of EM field in walls.

Normal modes of EM field corr. to Fourier
comps. A_k , with freq.

$$\omega_k = (\omega_p^2 + \epsilon^2 k^2)^{1/2}$$

Now in a "classical" superpos. of $|0\rangle$ and $|1\rangle$,

$$\langle A(z, t) \rangle \sim A_0 \exp -K(\omega) z \cos \omega t$$

$$[(\omega_p^2 - \omega^2)/\epsilon^2]^{1/2}$$

$$\rightarrow \langle A_k \rangle(t) \sim L_w^{-1/2} \frac{A_0}{K(\omega) + ik}$$

But, if $|k\rangle \equiv |0\rangle_L + \epsilon |1\rangle_L$

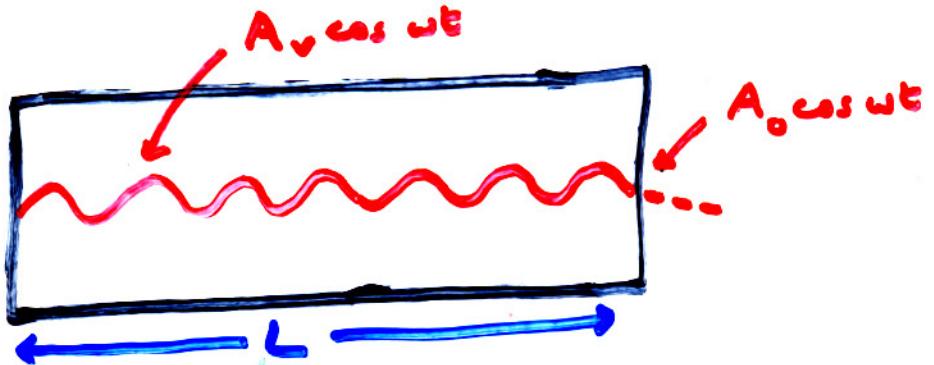
$$\epsilon_k^2 = \langle A_k \rangle^2 / \langle A_k^2 \rangle_0 \text{, and } \langle A_k^2 \rangle_0 = L_w^{-1} \left(\frac{\pi}{\epsilon_0 \omega_k} \right)$$

\Rightarrow degree of orthogonality of wave system

$$\sim \sum_k \epsilon_k^2 = L_w^{-1} \sum_k \frac{\epsilon_0 \omega_k A_0^2}{K^2(\omega) + k^2} = \epsilon_0 A_0^2 L_w^{-1} \sum_k \frac{c^2 \omega_k}{\omega_k^2 - \omega^2}$$

$$= \frac{\epsilon_0 A_0^2 c^2}{\pi} \frac{1}{2\pi} \int dk \frac{\omega_k}{\omega_k^2 - \omega^2} \sim \frac{\epsilon_0 A_0^2 c}{\pi} \ln \left(\frac{\lambda_L}{\lambda_D} \right) \text{ Duhre s. l.}$$

So :



degree of orthogonality of electrons in walls,
 $1 - \langle Kx_1 | x_2 \rangle^2 \approx \frac{\epsilon_0 A_v^2 c}{\pi} \times \text{bar term}$

But, from wall boundary condition,

$$A_v = (ik/k(\omega)) A_0$$

and, from equipartition, for a single-photon state,

$$L \cdot \epsilon_0 \omega^2 A_0^2 = \hbar \omega$$

Hence,

$$\frac{\epsilon_0 A_v^2 c}{\pi} = \left(\frac{k^2}{k^2(\omega)} \frac{\lambda}{L} \right) \cong \left(\frac{\lambda_L}{\lambda} \right) \left(\frac{\lambda_L}{L} \right)$$

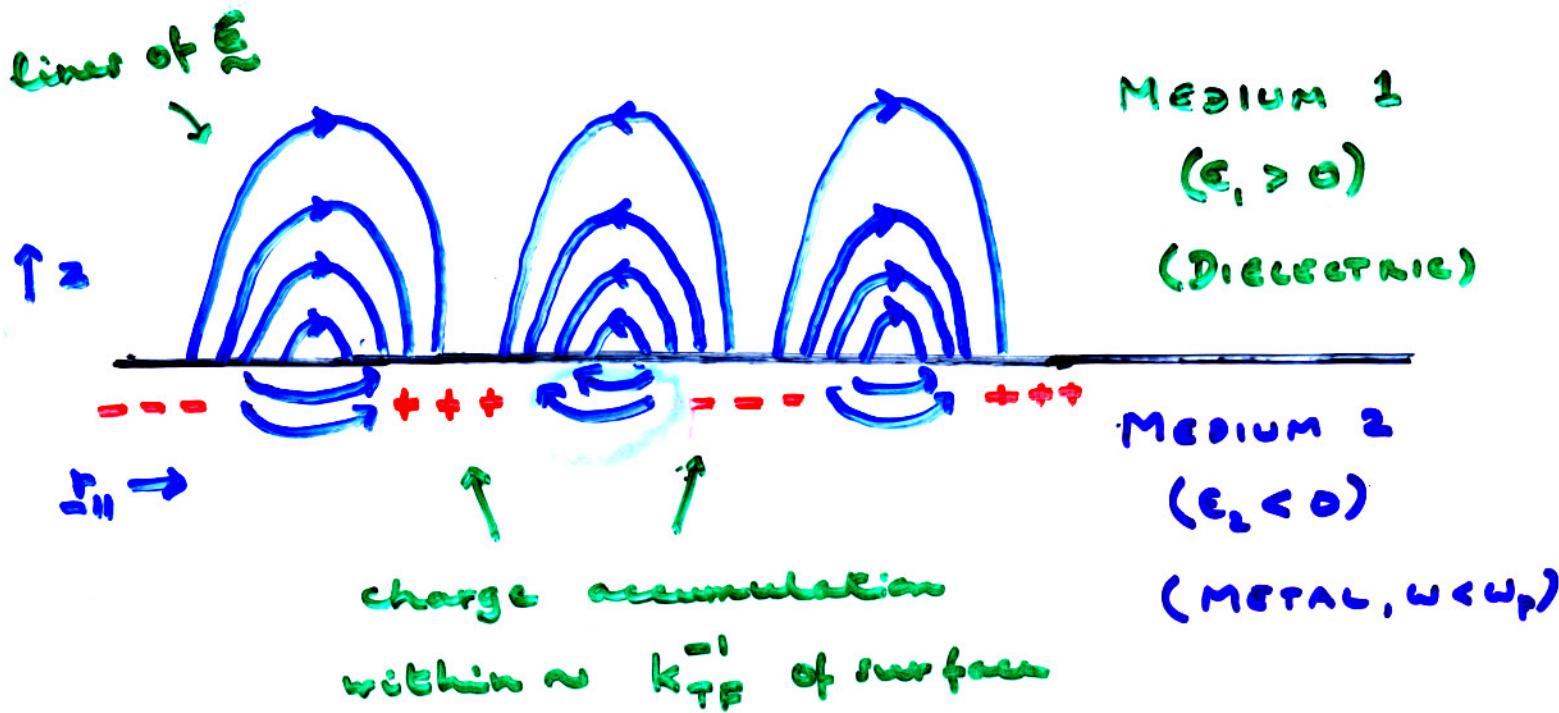
**CONCLUSION: UP TO NUMERICAL FACTORS,
 ELECTRONS IN WALLS ARE ENTANGLED
 ONLY TO DEGREE $(\lambda_L/L)(\lambda_L/\lambda) \ll 1$.**

END OF DISCUSSION

BACK TO SURFACE PLASMONS ...

(PITP 6)

WHAT IS A SURFACE PLASMON?



Explicit formula for vector potential $\underline{A}(r,t)$:

$$A(r,t) = R_e(A(z) \exp - i\omega t),$$

bound to
surface

$$A_z(r,t) = \hat{A}_0 \exp i k_{\parallel} r_{\parallel} \exp - k_z |z| \\ \times (\hat{k}_{\parallel} \pm (i \kappa_i / k_{\parallel}) \hat{z})$$

$$\kappa_i = \frac{\omega}{c} \cdot \left(\frac{-\epsilon_1 \epsilon_2}{\epsilon_1 + \epsilon_2} \right)^{1/2}, \quad k_{\parallel} = (\kappa_1 \kappa_2)^{1/2}$$

Hence for $|\epsilon_2| > \epsilon_1$, field in dielectric is mostly \perp surface, field in metal mostly \parallel surface.

For simplicity take 1 = vacuum ($\epsilon_1 = 1$),

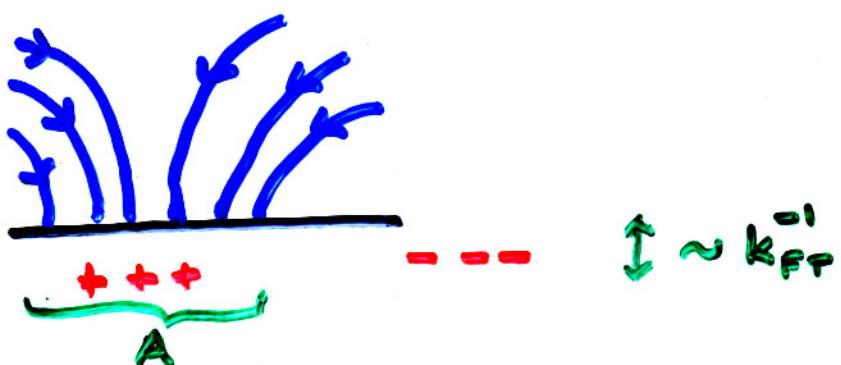
2 = perfect metal ($\epsilon_2 \approx 1 - \omega_p^2/\omega^2$), and $\omega \ll \omega_p$.

Then :

$$\kappa_1 = \frac{\omega}{\omega_1 \epsilon} , \kappa_2 = \frac{\omega_p}{\epsilon} (\equiv \lambda^{-1})$$

Can go through same argt. as for box, but for charge fluctuations easier to short-circuit:

$$(\epsilon_{z1} \gg \epsilon_{zz})$$



What is $\langle Q^2 \rangle / A$ when a single plasmon is present?

Since $\sigma \sim \epsilon_0 \epsilon_z'$, and normalize? \rightarrow

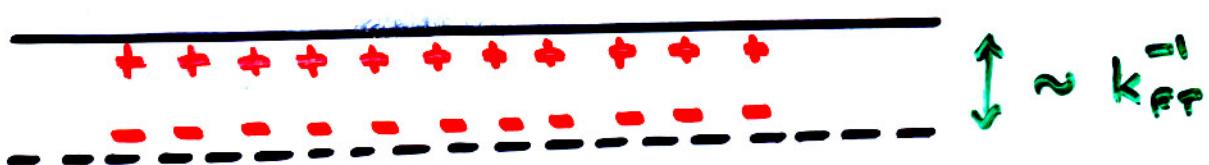
$$\epsilon_0 (\epsilon_z')^2 \kappa_1^{-1} A = \kappa \omega, \text{ result is } (Q \sim \sigma A)$$

$$[\langle Q^2 \rangle / A]_{\text{plasmon}} \sim \epsilon_0 \kappa \omega \cdot \kappa_1$$

Recap:

$$\langle Q^2 \rangle / A \text{ for single } \xrightarrow{\text{surface}} \text{ plasmon} \sim \epsilon_0 \cdot \hbar \omega_p \cdot k_1$$

Now, consider single "bulk" longitudinal plasmon of metal by itself: (or zero-point mode)



$\langle Q^2 \rangle_0$ is def. by

$$\langle Q^2 \rangle_0 / C \sim \hbar \omega_p$$

and $C = \epsilon_0 A / d$.

Hence,

$$\langle Q^2 \rangle_0 / A = \epsilon_0 \cdot \hbar \omega_p / d$$

Thus, finally,

$$\langle Q^2 \rangle_{\text{tot}} / \langle Q^2 \rangle_0 \sim \frac{C}{\omega_p} \cdot k_1 d \sim \left(\frac{\omega}{\omega_p}\right)^2 k_1 d$$

With realistic nos. this is $\lesssim 10^{-5}$!!

(Similar calc. for transverse current fluctuation gives $\sim (\omega/\omega_p)^3$).